

20TQ035/S 20TQ040/S 20TQ045/S

Technical Data Data Sheet N0673, Rev. - **Green Products**

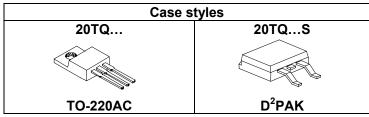
20TQ035/S/20TQ040/S/20TQ045/S SCHOTTKY RECTIFIER

Applications:

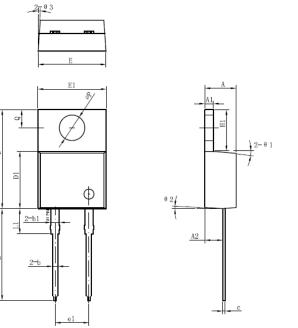
- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150°C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In Inches / mm



Symbol	Dimensions in millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.64	14.94	15.24	
D1	8.55	8.07	8.85	
E	10.01	10.16	10.31	
E1	9.98	10.18	10.38	
e1		5.08		
H1	6.04	6.24	6.44	
L	13.00	13.86	14.08	
L1		3.80		
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		5°		
Θ2		4 °		
Θ3		4 °		

TO-220AC

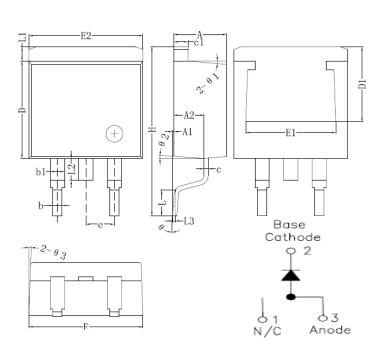
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Symbol	Dimensions in millimeters			
e y	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4 °		
e3		4 °		

D²PAK

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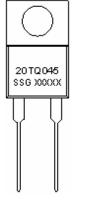


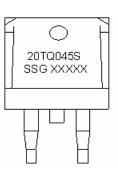
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Marking Diagram:





Where XXXXX is YYWWL

20TQ045	= Part Name
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

20TQ045

20TQ045S

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
20TQ045	TO-220AC (Pb-Free)	50pcs / tube
20TQ045S	D ² PAK (Pb-Free)	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	35(20TQ035) 40(20TQ040) 45(20TQ045)	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =116°C, rectangular wave form	20	A
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	480	A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 20A, Pulse, T _A = 25 °C	0.57	V
		@ 40A, Pulse, T _A = 25 °C	0.73	
Max. Forward Voltage Drop	V _{F1}	@ 20A, Pulse, T _A = 75 °C	0.51	V
		@ 40A, Pulse, T _A = 75 °C	0.67	
Max. Reverse Current (per	I _{R1}	$@V_R = rated V_R$	2.7	mA
leg) *		T _J = 25 °C		
Max. Reverse Current (per	I _{R1}	$@V_{R} = rated V_{R}$	105	mA
leg) *		T _J =100°C		
Max. Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C	1400	pF
(per leg)		f _{SIG} = 100KHz -1MHz		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	8.0	nH
(per leg)		package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

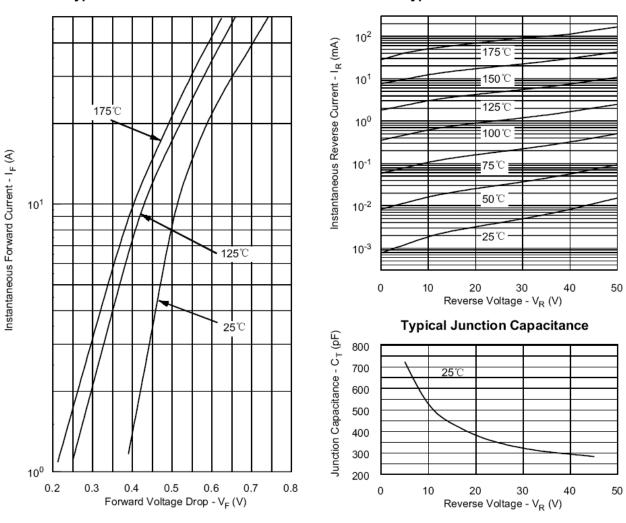
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	ΤJ	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per package)	$R_{ ext{ heta}JC}$	DC operation	1.5	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC D ² PAK ("S" for D ² PAK)			

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Typical Forward Characteristics

Typical Reverse Characteristics

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